74HC4024

7-stage binary ripple counter Rev. 4 — 29 September 2010

Product data sheet

1. **General description**

The 74HC4024 is a high-speed Si-gate CMOS device and is pin compatible with the 4024 of the 4000B series. The 74HC4024 is specified in compliance with JEDEC standard no. 7A.

The 74HC4024 is a 7-stage binary ripple counter with a clock input (CP), an overriding asynchronous master reset input (MR) and seven fully buffered parallel outputs (Q0 to Q6). The counter advances on the HIGH-to-LOW transition of CP. A HIGH on MR clears all counter stages and forces all outputs LOW, independent of the state of $\overline{\text{CP}}$. Each counter stage is a static toggle flip-flop.

Schmitt-trigger action in the clock input makes the circuit highly tolerant to slower clock rise and fall times.

2. **Features and benefits**

- Low-power dissipation
- Complies with JEDEC standard no. 7A
- ESD protection:
 - ◆ HBM JESD22-A114F exceeds 2000 V
 - MM JESD22-A115-A exceeds 200 V.
- Multiple package options
- Specified from −40 °C to +80 °C and from −40 °C to +125 °C.

Applications 3.

- Frequency dividing circuits
- Time delay circuits.



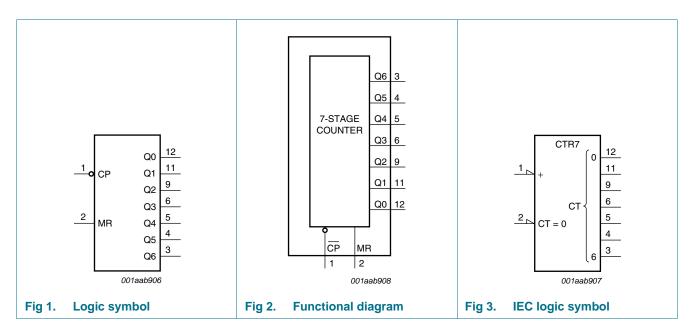
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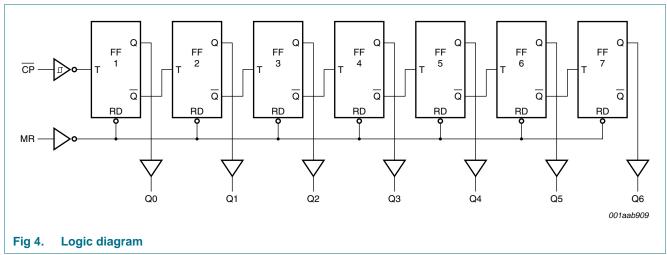
4. Ordering information

Table 1. Ordering information

Type number	Package						
	Temperature range	Name	Description	Version			
74HC4024N	−40 °C to +125 °C	DIP14	plastic dual in-line package; 14 leads (300 mil)	SOT27-1			
74HC4024D	–40 °C to +125 °C	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1			
74HC4024DB	–40 °C to +125 °C	SSOP14	plastic shrink small outline package; 14 leads; body width 5.3 mm	SOT337-1			
74HC4024PW	–40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	SOT402-1			

5. Functional diagram



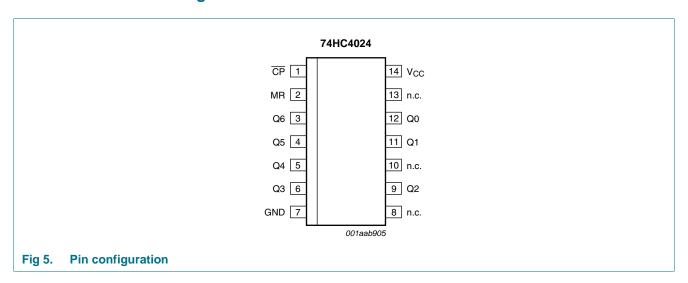


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6. Pinning information

6.1 Pinning



6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
CP	1	clock input (HIGH-to-LOW, edge-triggered)
MR	2	master reset input (active HIGH)
Q6, Q5, Q4, Q3, Q2, Q2, Q1, Q0	3, 4, 5, 6, 9, 11, 12	parallel output
GND	7	ground (0 V)
n.c.	8, 10, 13	not connected
V _{CC}	14	positive supply voltage

7. Functional description

Table 3. Function table[1]

Input		Output
MR	СР	Qn
Н	X	L
L	\uparrow	no change
	\	count

^[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care;

^{↑ =} LOW-to-HIGH clock transition;

 $[\]downarrow$ = HIGH-to-LOW clock transition.

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8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+7	V
I _{IK}	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{CC} + 0.5 \text{ V}$	-	±20	mA
I _{OK}	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	-	±20	mA
Io	output current	$V_O = -0.5 \text{ V to } V_{CC} + 0.5 \text{ V}$	-	±25	mA
I _{CC}	supply current		-	50	mA
I _{GND}	ground current		-50	-	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	DIP14 package	<u>[1]</u> -	750	mW
		SO14 package	[2] -	500	mW
		SSOP14 and TSSOP14 package	[3] _	500	mW

^[1] For DIP16 package: P_{tot} derates linearly with 12 mW/K above 70 °C.

9. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage		2.0	5.0	6.0	V
VI	input voltage		0	-	V_{CC}	V
Vo	output voltage		0	-	V_{CC}	V
$\Delta t/\Delta V$	input transition rise and fall	$V_{CC} = 2.0 \text{ V}$	-	-	625	ns/V
	rate	V _{CC} = 4.5 V	-	1.67	139	ns/V
		$V_{CC} = 6.0 \text{ V}$	-	-	83	ns/V
T _{amb}	ambient temperature		-40	-	+125	°C

^[2] For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 °C.

^[3] For (T)SSOP16 packages: Ptot derates linearly with 5.5 mW/K above 60 °C.

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10. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25	°C					
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	1.2	-	V
		V _{CC} = 4.5 V	3.15	2.4	-	V
		V _{CC} = 6.0 V	4.2	3.2	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	8.0	0.5	V
		V _{CC} = 4.5 V	-	2.1	1.35	V
		$V_{CC} = 6.0 \text{ V}$	-	2.8	1.8	V
V _{OH}	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_{O} = -20 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	V
		$I_{O} = -20 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	V
		$I_{O} = -20 \mu A; V_{CC} = 6.0 V$	5.9	6.0	-	V
		$I_{O} = -4 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.98	4.32	-	V
		$I_{O} = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.48	5.81	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_O = 20 \mu A$; $V_{CC} = 2.0 \text{ V}$	-	0	0.1	V
		$I_O = 20 \mu A$; $V_{CC} = 4.5 V$	-	0	0.1	V
		$I_O = 20 \mu A$; $V_{CC} = 6.0 \text{ V}$	-	0	0.1	V
		$I_{O} = 4 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	0.15	0.26	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	0.16	0.26	V
l _l	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±0.1	μΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 6.0$ V	-	-	8.0	μΑ
Cı	input capacitance		-	3.5	-	pF
T _{amb} = -40	0 °C to +85 °C					
V _{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5	-	-	V
		V _{CC} = 4.5 V	3.15	-	-	V
		V _{CC} = 6.0 V	4.2	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 2.0 V	-	-	0.5	V
		V _{CC} = 4.5 V	-	-	1.35	V
		V _{CC} = 6.0 V	-	-	1.8	V
VoH	HIGH-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_{O} = -20 \mu A; V_{CC} = 2.0 V$	1.9	-	-	V
		$I_{O} = -20 \mu A; V_{CC} = 4.5 V$	4.4	-	-	V
		$I_{O} = -20 \mu A; V_{CC} = 6.0 V$	5.9	-	-	V
		$I_{O} = -4 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.84	-	-	V
		$I_O = -5.2 \text{ mA}$; $V_{CC} = 6.0 \text{ V}$	5.34	-	-	V

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Table 6. Static characteristics ...continued
At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}	_	-71-		•
·OL	2011 to to to to apar to mago	$I_O = 20 \mu\text{A}; V_{CC} = 2.0 \text{V}$	_	-	0.1	V
		$I_O = 20 \mu A$; $V_{CC} = 4.5 \text{ V}$	_	_	0.1	V
		$I_O = 20 \mu A$; $V_{CC} = 6.0 \text{ V}$	_	_	0.1	V
		$I_O = 4 \text{ mA}; V_{CC} = 4.5 \text{ V}$	_	-	0.33	V
		$I_O = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.33	V
I _I	input leakage current	$V_1 = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$			±1.0	μΑ
I _{CC}	supply current	$V_1 = V_{CC}$ or GND; $I_0 = 0$ A; $V_{CC} = 6.0 \text{ V}$	_	-	80	μΑ
) °C to +125 °C	V = VCC 01 01VD, 10 = 0 A, VCC = 0.0 V			00	μΑ
V_{IH}	HIGH-level input voltage	V _{CC} = 2.0 V	1.5		_	V
VІН	i iiGi i-level iliput voltage	V _{CC} = 2.0 V V _{CC} = 4.5 V	3.15			V
			4.2			V
\ /	LOW level input valtage	$V_{CC} = 6.0 \text{ V}$		-		
V_{IL}	LOW-level input voltage	$V_{CC} = 2.0 \text{ V}$	-	-	0.5	V
		$V_{CC} = 4.5 \text{ V}$	-	-	1.35	V
.,	1110111	V _{CC} = 6.0 V	-	-	1.8	V
V_{OH}	HIGH-level output voltage	$V_{I} = V_{IH}$ or V_{IL}				
		$I_{O} = -20 \mu A; V_{CC} = 2.0 V$	1.9	-	-	V
		$I_{O} = -20 \mu A; V_{CC} = 4.5 V$	4.4	-	-	V
		$I_{O} = -20 \mu A; V_{CC} = 6.0 V$	5.9	-	-	V
		$I_{O} = -4 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.7	-	-	V
		$I_O = -5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	5.2	-	-	V
V_{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
		$I_O = 20 \mu A$; $V_{CC} = 2.0 \text{ V}$	-	-	0.1	V
		$I_O = 20 \mu A; V_{CC} = 4.5 V$	-	-	0.1	V
		$I_{O} = 20 \mu A; V_{CC} = 6.0 V$	-	-	0.1	V
		$I_{O} = 4 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.4	V
		$I_{O} = 5.2 \text{ mA}; V_{CC} = 6.0 \text{ V}$	-	-	0.4	V
I _I	input leakage current	$V_I = V_{CC}$ or GND; $V_{CC} = 6.0 \text{ V}$	-	-	±1.0	μА
I _{CC}	supply current	$V_{I} = V_{CC}$ or GND; $I_{O} = 0$ A; $V_{CC} = 6.0 \text{ V}$	-	-	160	μА

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11. Dynamic characteristics

Table 7. Dynamic characteristics

GND = 0 V; $t_r = t_f = 6 \text{ ns}$; $C_L = 50 \text{ pF}$; see Figure 7.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 25	°C					
t _{pd}	propagation delay	CP to Q0; see Figure 6	<u>[1]</u>			
		$V_{CC} = 2.0 \text{ V}$	-	47	175	ns
		$V_{CC} = 4.5 \text{ V}$	-	17	35	ns
		$V_{CC} = 6.0 \text{ V}$	-	14	30	ns
		$V_{CC} = 5.0 \text{ V}; C_L = 15 \text{ pF}$	-	14	-	ns
		Qn to Qn+1; see Figure 6	<u>[1]</u>			
		V _{CC} = 2.0 V	-	25	80	ns
		V _{CC} = 4.5 V	-	9	16	ns
		V _{CC} = 6.0 V	-	7	14	ns
t _{PHL}	HIGH to LOW	MR to Q0; see Figure 6				
	propagation delay	V _{CC} = 2.0 V	-	63	200	ns
		V _{CC} = 4.5 V	-	23	40	ns
		V _{CC} = 6.0 V	-	18	34	ns
t _t	transition time	see <u>Figure 6</u>	[2]			
		V _{CC} = 2.0 V	-	19	75	ns
		V _{CC} = 4.5 V	-	7	15	ns
		V _{CC} = 6.0 V	-	6	13	ns
t _W	pulse width	CP HIGH or LOW; see Figure 6				
		V _{CC} = 2.0 V	80	17	-	ns
		V _{CC} = 4.5 V	16	6	-	ns
		V _{CC} = 6.0 V	14	5	-	ns
		MR HIGH; see Figure 6				
		V _{CC} = 2.0 V	80	22	-	ns
		V _{CC} = 4.5 V	16	8	-	ns
		V _{CC} = 6.0 V	14	6	-	ns
t _{rec}	recovery time	MR to CP; see Figure 6				
		V _{CC} = 2.0 V	50	6	-	ns
		V _{CC} = 4.5 V	10	2	-	ns
		V _{CC} = 6.0 V	9	2	-	ns
f _{max}	maximum frequency	CP; see Figure 6				
	•	V _{CC} = 2.0 V	6.0	27	-	MHz
		V _{CC} = 4.5 V	30	82	-	MHz
		V _{CC} = 6.0 V	35	98	-	MHz
		V _{CC} = 5.0 V; C _L = 15 pF	-	90	-	MHz
C _{PD}	power dissipation capacitance	$V_I = GND \text{ to } V_{CC}$	[3] -	25	-	pF

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Table 7. Dynamic characteristics ...continued GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF; see <u>Figure 7</u>.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$T_{amb} = -40$	0 °C to +85 °C					
t _{pd}	propagation delay	CP to Q0; see Figure 6	<u>[1]</u>			
		V _{CC} = 2.0 V	-	-	220	ns
		V _{CC} = 4.5 V	-	-	44	ns
		V _{CC} = 6.0 V	-	-	37	ns
		Qn to Qn+1; see Figure 6	<u>[1]</u>			
		V _{CC} = 2.0 V	-	-	100	ns
		V _{CC} = 4.5 V	-	-	20	ns
		V _{CC} = 6.0 V	-	-	17	ns
t _{PHL}	HIGH to LOW	MR to Q0; see Figure 6				
	propagation delay	V _{CC} = 2.0 V	-	-	250	ns
		V _{CC} = 4.5 V	-	-	50	ns
		V _{CC} = 6.0 V	-	-	43	ns
t _t	transition time	see Figure 6	[2]			
		V _{CC} = 2.0 V	-	-	95	ns
		V _{CC} = 4.5 V	-	-	19	ns
		V _{CC} = 6.0 V	-	-	16	ns
t _W	pulse width	CP HIGH or LOW; see Figure 6				
		V _{CC} = 2.0 V	100	-	-	ns
		V _{CC} = 4.5 V	20	-	-	ns
		V _{CC} = 6.0 V	17	-	-	ns
		MR HIGH; see Figure 6				
		V _{CC} = 2.0 V	100	-	-	ns
		V _{CC} = 4.5 V	20	-	-	ns
		V _{CC} = 6.0 V	17	-	-	ns
t _{rec}	recovery time	MR to CP; see Figure 6				
		V _{CC} = 2.0 V	65	-	-	ns
		V _{CC} = 4.5 V	13	-	-	ns
		V _{CC} = 6.0 V	11	-	-	ns
max	maximum frequency	CP; see Figure 6				
		$V_{CC} = 2.0 \text{ V}$	4.8	-	-	MHz
		V _{CC} = 4.5 V	24	-	-	MHz
		V _{CC} = 6.0 V	28	_	_	MHz

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Table 7. Dynamic characteristics ...continued GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF; see <u>Figure 7</u>.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$T_{amb} = -4$	0 °C to +125 °C					
t_{pd}	propagation delay	CP to Q0; see Figure 6	<u>[1]</u>			
		V _{CC} = 2.0 V	-	-	265	ns
		V _{CC} = 4.5 V	-	-	53	ns
		V _{CC} = 6.0 V	-	-	45	ns
		Qn to Qn+1; see Figure 6	<u>[1]</u>			
		V _{CC} = 2.0 V	-	-	120	ns
		V _{CC} = 4.5 V	-	-	24	ns
		V _{CC} = 6.0 V	-	-	20	ns
t _{PHL}	HIGH to LOW	MR to Q0; see Figure 6				
	propagation delay	V _{CC} = 2.0 V	-	-	300	ns
		V _{CC} = 4.5 V	-	-	60	ns
		V _{CC} = 6.0 V	-	-	51	ns
t _t	transition time	see Figure 6	[2]			
		V _{CC} = 2.0 V	-	-	110	ns
		V _{CC} = 4.5 V	-	-	22	ns
		V _{CC} = 6.0 V	-	-	19	ns
t _W	pulse width	CP HIGH or LOW; see Figure 6				
		V _{CC} = 2.0 V	120	-	-	ns
		V _{CC} = 4.5 V	24	-	-	ns
		V _{CC} = 6.0 V	20	-	-	ns
		MR HIGH; see Figure 6				
		V _{CC} = 2.0 V	120	-	-	ns
		V _{CC} = 4.5 V	24	-	-	ns
		V _{CC} = 6.0 V	20	-	-	ns
t _{rec}	recovery time	MR to CP; see Figure 6				
		V _{CC} = 2.0 V	75	-	-	ns
		V _{CC} = 4.5 V	15	-	-	ns

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Table 7. Dynamic characteristics ...continued GND = 0 V; $t_r = t_f = 6$ ns; $C_L = 50$ pF; see <u>Figure 7</u>.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
f _{max} maximum frequency		CP; see Figure 6				
		$V_{CC} = 2.0 \text{ V}$	4.0	-	-	MHz
		V _{CC} = 4.5 V	20	-	-	MHz
		V _{CC} = 6.0 V	24	-	-	MHz

- [1] t_{pd} is the same as t_{PLH} and t_{PHL} .
- [2] t_t is the same as t_{THL} and t_{TLH} .
- [3] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum (C_L \times V_{CC}^2 \times f_o)$ where:

 f_i = input frequency in MHz;

f_o = output frequency in MHz;

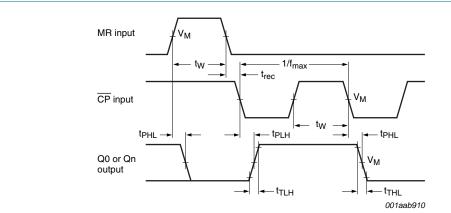
C_L = output load capacitance in pF;

V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\sum (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs.

12. Waveforms

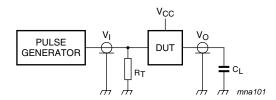


Also showing the master reset (MR) pulse width, the master reset to output (Qn) propagation delays and the master reset to clock $\overline{(CP)}$ recovery time.

 $V_M = 0.5 \times V_I$.

Fig 6. Waveforms showing the clock (CP) to output (Qn) propagation delays, the clock pulse width, the output transition times and the maximum clock frequency

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Test data is given in Table 8.

Definitions for test circuit:

 R_T = Termination resistance should be equal to output impedance Z_o of the pulse generator.

 C_L = Load capacitance including jig and probe capacitance.

Fig 7. Test circuit for measuring switching times

Table 8. Test data

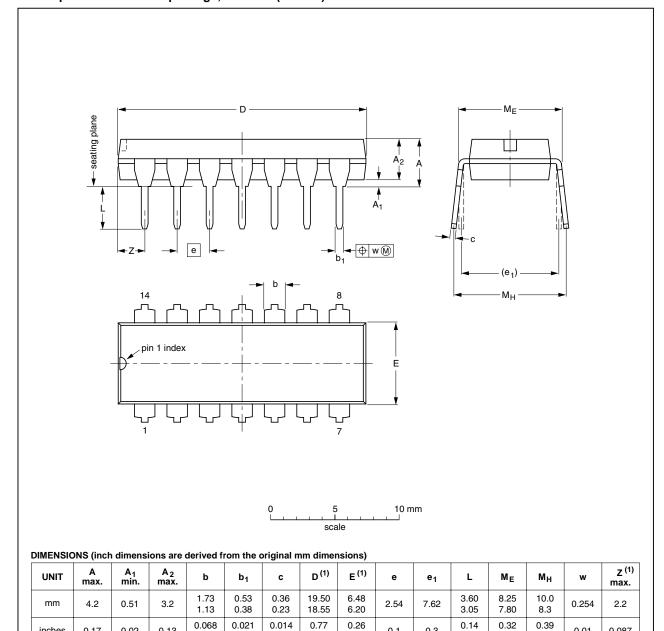
Supply	Input		Load
V _{CC}	VI	t _r , t _f	C _L
2.0 V	V _{CC}	6 ns	50 pF
4.5 V	V _{CC}	6 ns	50 pF
6.0 V	V _{CC}	6 ns	50 pF
5.0 V	V _{CC}	6 ns	15 pF

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13. Package outline

DIP14: plastic dual in-line package; 14 leads (300 mil)

SOT27-1



inches

0.17

0.02

0.13

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

0.044

0.015

0.009

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA	PROJECTION		ISSUE DATE	
SOT27-1	050G04	MO-001	SC-501-14			99-12-27 03-02-13	

0.3

Fig 8. Package outline SOT27-1 (DIP14)

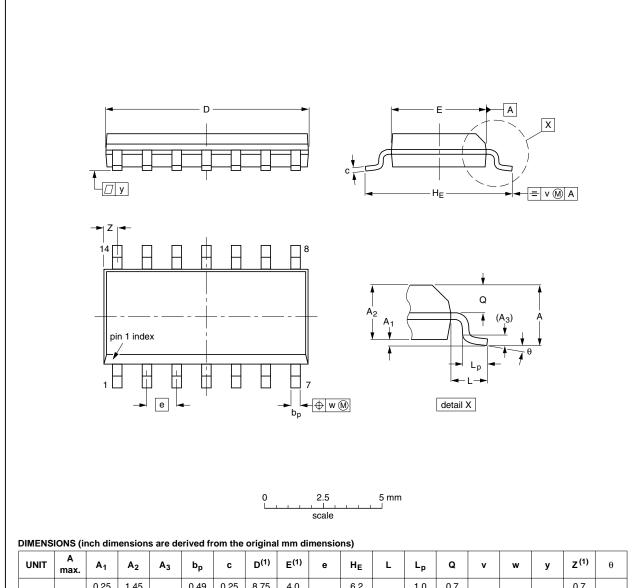
74HC4024

0.01

0.087

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	8.75 8.55	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01	1	0.0100 0.0075	0.35 0.34	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

0	UTLINE		REFER	EUROPEAN	ISSUE DATE			
VI	ERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
S	OT108-1	076E06	MS-012				99-12-27 03-02-19	

Fig 9. Package outline SOT108-1 (SO14)

74HC4024

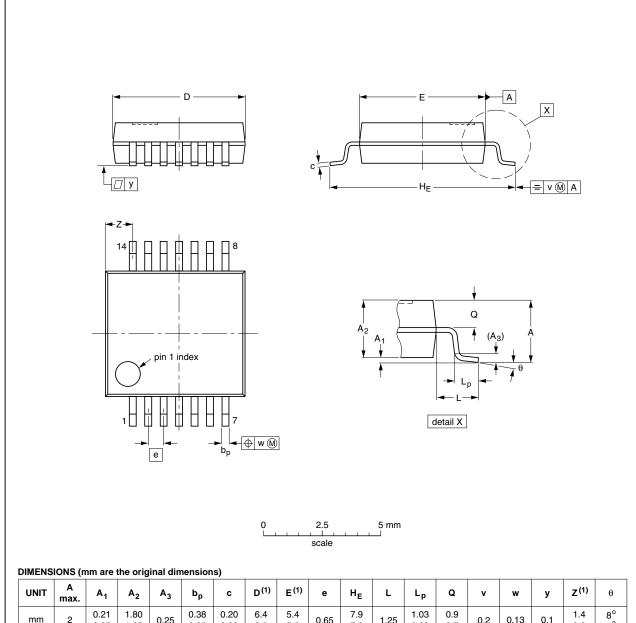
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SSOP14: plastic shrink small outline package; 14 leads; body width 5.3 mm

SOT337-1



UNIT	A max.	A ₁	A ₂	A ₃	b _p	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	v	w	у	Z ⁽¹⁾	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	6.4 6.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	1.4 0.9	8° 0°

Note

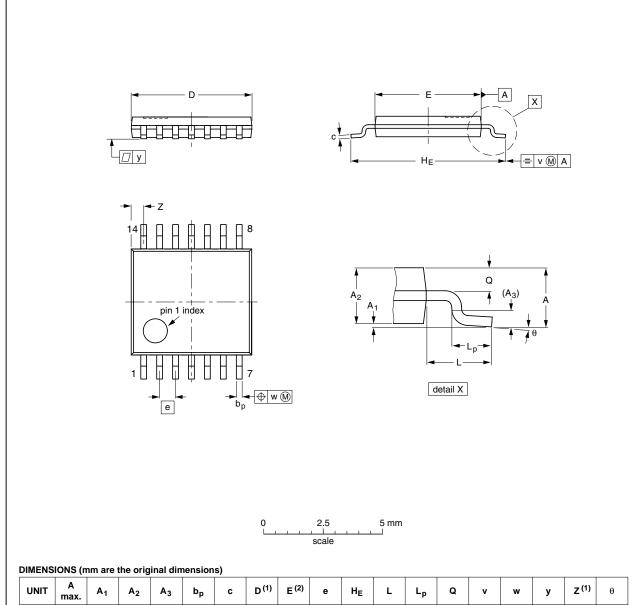
1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	135UE DATE	
SOT337-1		MO-150				99-12-27 03-02-19	

Fig 10. Package outline SOT337-1 (SSOP14)

TSSOP14: plastic thin shrink small outline package; 14 leads; body width 4.4 mm

SOT402-1



UNIT	A	Δ.	A2		h	Ĺ	D ⁽¹⁾	F (2)	_	He		1	0	v	w	v	7 (1)	А
Olviii	max.	A ₁	72	А3	Вp	·			e	''E	_	- p	3	•	W	У	1	U
mm	1.1	0.15	0.95	0.25	0.30	0.2	5.1	4.5	0.65	6.6	1	0.75	0.4	0.2	0.13	0.1	0.72	8°
		0.05	0.80	0.20	0.19	0.1	4.9	4.3	0.00	6.2		0.50	0.3	0	0	0	0.38	0°

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

	ISSUE DATE	
PROJECTION	ISSUE DATE	
	99-12-27 03-02-18	
	<u> </u>	

Fig 11. Package outline SOT402-1 (TSSOP14)

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14. Abbreviations

Table 9. Abbreviations

Acronym	Description
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model

15. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74HC4024 v.4	20100929	Product data sheet	-	74HC4024 v.3
Modifications:		of this data sheet has been of NXP Semiconductors.	en redesigned to con	nply with the new identity
	 Legal texts 	have been adapted to the	new company name	e where appropriate.
	• Figure 1: ir	version dot removed for M	IR pin.	
	• <u>Table 4</u> : de	rating factor changed for (T)SSOP14 package	s.
	• <u>Table 5</u> : t _r ,	t_f changed to $\Delta t/\Delta V$.		
74HC4024 v.3	20041112	Product data sheet	-	74HC_HCT4024_CNV v.2
74HC_HCT4024_CNV v.2	19970901	Product specification	-	74HC_HCT4024 v.1
74HC_HCT4024 v.1	19901201	Product specification	-	-
·				

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16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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